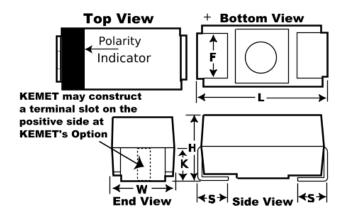


T498D476M006ZTE800

Obsolete

B45196P, Tantalum, MnO2 Tantalum, High Temperature, 47 uF, 20%, 6.3 VDC, SMD, Molded, High Temperature, N/A, 800 mOhms, 7343, Height Max = 3.1mm



General Information		
Series	B45196P	
Dielectric	MnO2 Tantalum	
Style	SMD Chip	
Description	SMD, Molded, High Temperature	
Features	High Temperature	
RoHS	Yes	
Termination	Tin	
AEC-Q200	No	
Notes	Obsolete. Old Part Number [Obsolete] Was B45196P1476M409.	

Dimensions		
Footprint	7343	
L	7.3mm +/-0.3mm	
W	4.3mm +/-0.3mm	
Н	2.8mm +/-0.3mm	
S	1.3mm +/-0.3mm	
F	2.4mm +/-0.1mm	
K	1.8mm TYP	

Specifications	
Capacitance	47 uF
Capacitance Tolerance	20%
Voltage DC	6.3 VDC (85C), 5.02 VDC (125C), 4.22 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
Dissipation Factor	4.5%
Failure Rate	N/A
Resistance	0.8 Ohms (100kHz)
Leakage Current	3 uA

Packaging Specifications			
Packaging	T&R, 178mm		
Packaging Quantity	750		

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